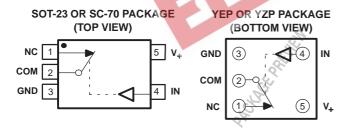
SCDS187 - FEBRUARY 2005

Description

The TS5A3167 is a single-pole single-throw (SPST) analog switch that is designed to operate from 1.65 V to 5.5 V. The device offers a low ON-state resistance. The device has excellent total harmonic distortion (THD) performance and consumes very low power. These features make this device suitable for portable audio applications.

Applications

- Cell Phones
- PDAs
- Portable Instrumentation
- Audio and Video Signal Routing
- Low-Voltage Data-Acquisition Systems
- Communication Circuits
- Modems
- Hard Drives
- Computer Peripherals
- Wireless Terminals and Peripherals
- Microphone Switching Notebook Docking



FUNCTION TABLE

IN	NC TO COM, COM TO NC
L	ON
Н	OFF

Features

- Isolation in the Powered-Off Mode, V₊ = 0
- Low ON-State Resistance (0.9 Ω)
- Control Inputs Are 5.5-V Tolerant
- Low Charge Injection
- Low Total Harmonic Distortion (THD)
- 1.65-V to 5.5-V Single-Supply Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
 2000-V Human-Body Model
 (A114-B, Class II)
 1000-V Charged-Device Model (C101)

Summary of Characteristics

 $V_{+} = 5 \text{ V}, T_{\Delta} = 25^{\circ}\text{C}$

Configuration	Single Pole Single Throw (SPST)
Number of channels	1
ON-state resistance (ron)	0.9 Ω
ON-state resistance flatness (ron(flat))	0.15 Ω
Turn-on/turn-off time (ton/toff)	7.5 ns/12 ns
Charge injection (Q _C)	1 pC
Bandwidth (BW)	200 MHz
OFF isolation (OISO)	-64 dB at 1 MHz
Total harmonic distortion (THD)	0.005%
Leakage current (ICOM(OFF))	±20 nA
Power-supply current (I+)	0.5 μΑ
Package option	5-pin DSBGA, SOT-23, or SC-70



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



SCDS187 - FEBRUARY 2005

ORDERING INFORMATION

TA	PACKAGE(1)		ORDERABLE PART NUMBER	TOP-SIDE MARKING(2)
	NanoStar™ – WCSP (DSBGA) 0.23-mm Large Bump – YEP	Tono and and	TS5A3167YEPR	- DREVIEW
-40°C to 85°C	NanoFree™ – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free)	Tape and reel	TS5A3167YZPR	PACKAGE PREVIEW
	SOT (SOT-23) – DBV	Tape and reel	TS5A3167DBVR	JAT
	SOT (SC-70) – DCK	Tape and reel	TS5A3167DCKR	JG

⁽¹⁾ Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

Absolute Minimum and Maximum Ratings(1)(2)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
٧+	Supply voltage range(3)		-0.5	6.5	V
V _{NC} V _{COM}	Analog voltage range(3)(4)(5)	A. E.	-0.5	V ₊ + 0.5	V
ΙK	Analog port diode current	V _{NC} , V _{COM} < 0	-50		mA
INC	On-state switch current	W W OUT TO	-200	200	4
ІСОМ	On-state peak switch current ⁽⁶⁾	V_{NC} , $V_{COM} = 0$ to V_+	-400	400	mA
٧ _I	Digital input voltage range(3)(4)		-0.5	6.5	V
Ικ	Digital input clamp current	V _I < 0	-50		mA
I ₊	Continuous current through V ₊	11		100	mA
IGND	Continuous current through GND	7	-100		mA
		DBV package		206	
θJΑ	Package thermal impedance(7)	DCK package		252	°C/W
		YEP/YZP package		132	
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.

- (2) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
- (3) All voltages are with respect to ground, unless otherwise specified.
- (4) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- (5) This value is limited to 5.5 V maximum.
- (6) Pulse at 1-ms duration < 10% duty cycle
- (7) The package thermal impedance is calculated in accordance with JESD 51-7.

⁽²⁾ DBV/DCK: The actual top-side marking has one additional character that designates the assembly/test site.

YEP/YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, ● = Pb-free).





Electrical Characteristics for 5-V Supply⁽¹⁾ $V_+ = 4.5 \text{ V}$ to 5.5 V, $T_A = -40^{\circ}\text{C}$ to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	ONS	TA	٧+	MIN	TYP	MAX	UNIT
Analog Switch									
Analog signal range	V _{COM} , V _{NC}					0		٧+	>
Peak ON resistance	<u>.</u> .	$0 \le V_{NC} \le V_+$	Switch ON,	25 °C	4.5 V		0.8	1.1	Ω
reak ON resistance	^r peak	$I_{COM} = -100 \text{ mA},$	See Figure 13	Full	4.5 V			1.2	52
ON-state resistance	ran	$V_{NC} = 2.5 V,$	Switch ON,	25°C	4.5 V		0.7	0.9	Ω
ON State resistance	ron	$I_{COM} = -100 \text{ mA},$	See Figure 13	Full	7.5 V			1	22
ON-state resistance		$0 \le V_{NC} \le V_{+},$ $I_{COM} = -100 \text{ mA}$	Switch ON,	25°C	451/		0.15		0
flatness	ron(flat)	V _{NC} = 1 V, 1.5 V, 2.5 V,	See Figure 13	25°C	4.5 V		0.09	0.15	Ω
		I _{COM} = -100 mA		Full				0.15	
		$V_{NC} = 1 \text{ V}, V_{COM} = 4.5 \text{ V},$		25°C		-20	4	20	
NC	INC(OFF)	or V _{NC} = 4.5 V, V _{COM} = 1 V	Switch OFF,	Full	5.5 V	-20		20	nA
OFF leakage current	hio/Piv/Pose	$V_{NC} = 0 \text{ to } 5.5 \text{ V},$	See Figure 14	25°C	οV	-5	0.4	5	μΑ
	INC(PWROFF)	V _{COM} = 5.5 V to 0	3. 3°	Full	O V	-15		15	μΛ
	1.	$V_{COM} = 1 \text{ V}, V_{NC} = 4.5 \text{ V},$	2373	25°C		-20	4	20	
COM	ICOM(OFF)	or $V_{COM} = 4.5 \text{ V}, V_{NC} = 1 \text{ V}$	Switch OFF,	Full	5.5 V	-100		100	nA
OFF leakage current		$V_{COM} = 5.5 \lor to 0,$	See Figure 14	25°C	0 V	-5	0.4	5	^
	COM(PWROFF)	$V_{NC} = 0$ to 5.5 \vee		Full	0 0	-15		15	μΑ
NC	hioroni	V _{NC} = 1 V, V _{COM} = Open,	Switch ON,	25°C	5.5 V	-2	0.3	2	nA
ON leakage current	INC(ON)	$V_{NC} = 4.5 \text{ V}, V_{COM} = \text{Open},$	See Figure 15	Full	3.5 V	-20		20	IIA
COM		V _{COM} = 1 V, V _{NC} = Open,	Switch ON,	25°C	5.51/	-2	0.3	2	
ON leakage current	ICOM(ON)	$V_{COM} = 4.5 \text{ V}, V_{NC} = \text{Open},$	See Figure 15	Full	5.5 V	-20		20	nA
Digital Control Input ((IN)								
Input logic high	VIH			Full		2.4		5.5	V
Input logic low	VIL			Full		0		8.0	V
lanut lankaga aurrant	La color	V. FFVor0		25°C	E E V	-2	0.3	2	~ ^
Input leakage current	I _{IH} , I _{IL}	$V_{I} = 5.5 \text{ V or } 0$		Full	5.5 V	-20		20	nA

⁽¹⁾ The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum



SCDS187 – FEBRUARY 2005

Electrical Characteristics for 5-V Supply⁽¹⁾ (continued) $V_+ = 4.5 \text{ V}$ to 5.5 V, $T_A = -40 ^{\circ}\text{C}$ to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST COI	NDITIONS	TA	V ₊	MIN	TYP	MAX	UNIT
Dynamic	1			•					
Turn-on time	tou	$V_{COM} = V_+,$	C _L = 35 pF,	25°C	5 V	2.5	4.5	7	ns
rain on time	tON	$R_L = 50 \Omega$,	See Figure 17	Full	4.5 V to 5.5 V	1.5		7.5	115
Turn-off time	torr	$V_{COM} = V_+,$	$C_L = 35 pF$,	25°C	5 V	6	9	11.5	ns
Tarri on anno	tOFF	$R_L = 50 \Omega$,	See Figure 17	Full	4.5 V to 5.5 V	4		12.5	113
Charge injection	QC	V _{GEN} = 0, R _{GEN} = 0,	C _L = 1 nF, See Figure 20	25°C	5 V		1		pC
NC OFF capacitance	C _{NC(OFF)}	V _{NC} = V ₊ or GND, Switch OFF,	See Figure 16	25°C	5 V		19		pF
COM OFF capacitance	C _{COM(OFF)}	V _{COM} = V ₊ or GND, Switch OFF,	See Figure 16	25°C	5 V		18		pF
NC ON capacitance	C _{NC(ON)}	V _{NC} = V ₊ or GND, Switch ON,	See Figure 16	25°C	5 V		35.5		pF
COM ON capacitance	C _{COM(ON)}	V _{COM} = V ₊ or GND, Switch ON,	See Figure 16	25°C	5 V		35.5		pF
Digital input capacitance	Cl	$V_{I} = V_{+}$ or GND,	See Figure 16	25° C	5 V		2		pF
Bandwidth	BW	R_L = 50 Ω, Switch ON,	See Figure 18	25°C	5 V		200		MHz
OFF isolation	O _{ISO}	R_L = 50 Ω, f = 1 MHz,	Switch OFF, See Figure 19	25°C	5 V		-64		dB
Total harmonic distortion	THD	$R_L = 600 \Omega,$ $C_L = 50 pF,$	f = 20 Hz to 20 kHz, See Figure 21	25°C	5 V		0.005		%
Supply									
Positive supply current	I ₊	$V_1 = V_+ \text{ or GND},$	Switch ON or OFF	25°C Full	5.5 V		0.01	0.1	μА

⁽¹⁾ The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum





Electrical Characteristics for 3.3-V Supply⁽¹⁾ $V_+ = 3 \text{ V to } 3.6 \text{ V}, T_A = -40^{\circ}\text{C} \text{ to } 85^{\circ}\text{C} \text{ (unless otherwise noted)}$

PARAMETER	SYMBOL	TEST CONDITION	ONS	TA	٧+	MIN	TYP	MAX	UNIT
Analog Switch	•								
Analog signal range	V _{COM} , V _{NC}					0		٧+	V
Peak ON resistance	r .	$0 \le V_{NC} \le V_+$	Switch ON,	25 °C	3 V		1.1	1.5	Ω
reak ON resistance	^r peak	$I_{COM} = -100 \text{ mA},$	See Figure 13	Full	3 V			1.7	52
ON-state resistance	ran	V _{NC} = 2 V,	Switch ON,	25°C	3 V		1	1.4	Ω
ON State resistance	r _{on}	$I_{COM} = -100 \text{ mA},$	See Figure 13	Full	- V			1.5	32
ON-state resistance		$0 \le V_{NC} \le V_+,$ $I_{COM} = -100 \text{ mA}$	Switch ON,	25°C			0.2		_
flatness	ron(flat)	V _{NC} = 2 V, 0.8 V,	See Figure 13	25°C	3 V		0.09	0.15	Ω
		I _{COM} = -100 mA		Full				0.15	
		$V_{NC} = 1 \text{ V}, V_{COM} = 3 \text{ V},$		25°C		-2	0.5	2	
NC	INC(OFF)	or $V_{NC} = 3 \text{ V}, V_{COM} = 1 \text{ V}$	Switch OFF,	Full	3.6 V	-20		20	nA
OFF leakage current	h logh roose	$V_{NC} = 0 \text{ to } 3.6 \text{ V},$	See Figure 14	25°C	- o v	1	0.1	1	μА
	INC(PWROFF)	V _{COM} = 3.6 V to 0		Full	0 V	-5		5	μΑ
		$V_{COM} = 1 \text{ V}, V_{NC} = 3 \text{ V},$	36.3	25°C	O	-2	0.5	20	
COM	ICOM(OFF)	or V _{COM} = 3 V, V _{NC} = 1 V	Switch OFF,	Full	3.6 V	-20		20	nA
OFF leakage current		V _{COM} = 3.6 V to 0,	See Figure 14	25°C	0 V	-1	0.1	1	μΑ
	COM(PWROFF)	$V_{NC} = 0 \text{ to } 3.6 \text{ V}$		Full	0 0	-5		5	μΑ
NC		$V_{NC} = 1 V$, $V_{COM} = Open$,	Switch ON,	25°C	1/	-2	0.2	2	
ON leakage current	INC(ON)	$V_{NC} = 3 V, V_{COM} = Open,$	See Figure 15	Full	3.6 V	-20		20	nA
COM		$V_{COM} = 1 \text{ V}, V_{NC} = \text{Open},$	Switch ON,	25°C		-2	0.2	2	
ON leakage current	ICOM(ON)	or V _{COM} = 3 V, V _{NC} = Open,	See Figure 15	Full	3.6 V	-20		20	nA
Digital Control Input	(IN)								
Input logic high	VIH			Full		2		5.5	V
Input logic low	V _{IL}			Full		0		0.8	V
Input leakage current	lu i lu	V _I = 5.5 V or 0		25°C	3.6 V	-2	0.3	2	nA
input leakage current	I _{IH} , I _{IL}	VI = 5.5 V 01 U		Full	3.0 V	-20		20	IIA

⁽¹⁾ The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum



SCDS187 – FEBRUARY 2005

Electrical Characteristics for 3.3-V Supply⁽¹⁾ (continued) $V_{+} = 3 \text{ V to } 3.6 \text{ V}, T_{A} = -40 ^{\circ}\text{C to } 85 ^{\circ}\text{C (unless otherwise noted)}$

PARAMETER	SYMBOL	TEST CO	NDITIONS	T_{A}	٧+	MIN	TYP	MAX	UNIT
Dynamic	•			•					
Turn-on time	ton	$V_{COM} = V_+,$	$C_L = 35 pF$,	25°C	3.3 V	2	5	10	ns
Turr on time	tON	$R_L = 50 \Omega$,	See Figure 17	Full	3 V to 3.6 V	1.5		11	115
Turn-off time	tOFF	$V_{COM} = V_+,$	$C_L = 35 pF$,	25°C	3.3 V	6.5	9	12	ns
	*OFF	$R_L = 50 \Omega$,	See Figure 17	Full	3 V to 3.6 V	4		13	110
Charge injection	QC	V _{GEN} = 0, R _{GEN} = 0,	$C_L = 1 \text{ nF},$ See Figure 20	25°C	3.3 V		1		рC
NC OFF capacitance	C _{NC(OFF)}	V _{NC} = V ₊ or GND, Switch OFF,	See Figure 16	25°C	3.3 V		19		pF
COM OFF capacitance	C _{COM(OFF)}	V _{COM} = V ₊ or GND, Switch OFF,	See Figure 16	25°C	3.3 V		18		pF
NC ON capacitance	C _{NC(ON)}	V _{NC} = V ₊ or GND, Switch ON,	See Figure 16	25°C	3.3 V		36		pF
COM ON capacitance	C _{COM(ON)}	V _{COM} = V ₊ or GND, Switch ON,	See Figure 16	25°C	3.3 V		36		pF
Digital input capacitance	Cl	$V_I = V_+ \text{ or GND},$	See Figure 16	25°C	3.3 V		2		pF
Bandwidth	BW	R_L = 50 Ω, Switch ON,	See Figure 18	25°C	3.3 V		200		MHz
OFF isolation	O _{ISO}	$R_L = 50 \Omega$, f = 1 MHz,	Switch OFF, See Figure 19	25°C	3.3 V		-64		dB
Total harmonic distortion	THD	$R_L = 600 \Omega,$ $C_L = 50 pF,$	f = 20 Hz to 20 kHz, See Figure 21	25°C	3.3 V		0.01		%
Supply									
Positive supply current	I ₊	$V_{l} = V_{+}$ or GND,	Switch ON or OFF	25°C Full	3.6 V		0.01	0.1 0.25	μА

⁽¹⁾ The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum





Electrical Characteristics for 2.5-V Supply(1) $V_+ = 2.3 \text{ V}$ to 2.7 V, $T_A = -40 ^{\circ}\text{C}$ to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	ONS	TA	٧+	MIN	TYP	MAX	UNIT
Analog Switch		1							
Analog signal range	V _{COM} , V _N C					0		٧+	V
Dools ON registers		$0 \le V_{NC} \le V_+$	Switch ON,	25 °C	221		1.4	2.2	
Peak ON resistance	^r peak	$I_{COM} = -8 \text{ mA},$	See Figure 13	Full	2.3 V			2.4	Ω
ON state resistance	_	V _{NC} = 1.8 V,	Switch ON,	25°C	221		1.2	1.8	
ON-state resistance	ron	$I_{COM} = -8 \text{ mA},$	See Figure 13	Full	2.3 V			2	Ω
		$0 \le V_{NC} \le V_+$		25°C			0.5		İ
ON-state resistance	ron(flat)	ICOM = -8 mA	Switch ON,		2.3 V				Ω
flatness	·on(nat)	$V_{NC} = 0.8 \text{ V}, 1.8 \text{ V},$	See Figure 13	25°C	2.0 (0.2	0.5	
		ICOM = -8 mA		Full				0.5	
	hio(o==)	$V_{NC} = 0.5 \text{ V}, V_{COM} = 2.3 \text{ V},$		25°C	2.7 V	-2	0.5	2	nA
NC	INC(OFF)	$V_{NC} = 2.3 \text{ V}, V_{COM} = 0.5 \text{ V}$	Switch OFF,	Full	2.7 V	-20		20	na I
OFF leakage current		V _{NC} = 0 to 2.7 V,	See Figure 14	25°C	- 01/	-1	0.1	1	•
	INC(PWROFF)	$V_{COM} = 2.7 \text{ V to } 0$		Full	0 V	-5		5	μΑ
		$V_{COM} = 0.5 \text{ V}, V_{NC} = 2.3 \text{ V},$	建 3	25°C	5	-2	0.5	2	
COM	ICOM(OFF)	or $V_{COM} = 2.3 \text{ V}, V_{NC} = 0.5 \text{ V}$	Switch OFF,	Full	2.7 V	-20		20	nA
OFF leakage current		V _{COM} = 2.7 V to 0,	See Figure 14	25°C	0 V	-1	0.1	1	^
	COM(PWROFF)	$V_{NC} = 0$ to 2.7 \vee		Full	0 0	-5		5	μΑ
NC		$V_{NC} = 0.5 \text{ V}, V_{COM} = \text{Open},$	Switch ON,	25°C		-2	0.1	2	
ON leakage current	INC(ON)	or $V_{NC} = 2.3 \text{ V}, V_{COM} = \text{Open},$	See Figure 15	Full	2.7 V	-20		20	nA
COM		$V_{COM} = 0.5 \text{ V}, V_{NC} = \text{Open},$	Switch ON,	25°C		-2	0.1	2	1 -
ON leakage current	ICOM(ON)	or $V_{COM} = 2.3 \text{ V}, V_{NC} = \text{Open},$	See Figure 15	Full	2.7 V	-20		20	nA
Digital Control Input	(IN)								
Input logic high	VIH			Full		1.8		5.5	V
Input logic low	V _{IL}			Full		0		0.6	V
Input leakage	la chi	V:		25°C	271/	-2	0.3	2	n 1
current	I _{IH} , I _{IL}	V _I = 5.5 V or 0		Full	2.7 V	-20		20	nA

⁽¹⁾ The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum



SCDS187 – FEBRUARY 2005

Electrical Characteristics for 2.5-V Supply⁽¹⁾ (continued) $V_+ = 2.3 \text{ V}$ to 2.7 V, $T_A = -40 ^{\circ}\text{C}$ to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CO	ONDITIONS	TA	٧+	MIN	TYP	MAX	UNIT
Dynamic	•			•					•
Turn-on time	ton	$V_{COM} = V_+,$	$C_L = 35 pF$,	25°C	2.5 V	3	7	10	ns
Turr on time	tON	$R_L = 50 \Omega$,	See Figure 17	Full	2.3 V to 2.7 V	2.5		1.5	115
Turn-off time	tOFF	$V_{COM} = V_+,$	$C_L = 35 pF$,	25°C	2.5 V	6.5	9.5	13	ns
	OFF	$R_L = 50 \Omega$,	See Figure 17	Full	2.3 V to 2.7 V	5		15	113
Charge injection	QC	V _{GEN} = 0, R _{GEN} = 0,	$C_L = 1 \text{ nF},$ See Figure 20	25°C	2.5 V		1		pC
NC OFF capacitance	C _{NC(OFF)}	$V_{NC} = V_{+}$ or GND, Switch OFF,	See Figure 16	25°C	2.5 V		19		pF
COM OFF capacitance	C _{COM} (OFF)	V _{COM} = V ₊ or GND, Switch OFF,	See Figure 16	25°C	2.5 V		18		pF
NC ON capacitance	C _{NC(ON)}	V _{NC} = V ₊ or GND, Switch ON,	See Figure 16	25°C	2.5 V		36.5		pF
COM ON capacitance	C _{COM(ON)}	V _{COM} = V ₊ or GND, Switch ON,	See Figure 16	25°C	2.5 V		36.5		pF
Digital input capacitance	Cl	$V_{I} = V_{+}$ or GND,	See Figure 16	25°C	2.5 V		2		pF
Bandwidth	BW	R_L = 50 Ω, Switch ON,	See Figure 18	25°C	2.5 V		200		MHz
OFF isolation	O _{ISO}	$R_L = 50 \Omega$, f = 1 MHz,	Switch OFF, See Figure 19	25°C	2.5 V		-64		dB
Total harmonic distortion	THD	$R_L = 600 \Omega,$ $C_L = 50 pF,$	f = 20 Hz to 20 kHz, See Figure 21	25°C	2.5 V		0.02		%
Supply									
Positive supply current	1+	$V_1 = V_+ \text{ or GND},$	Switch ON or OFF	25°C Full	2.7 V		0.01	0.1 0.15	μА

⁽¹⁾ The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum





Electrical Characteristics for 1.8-V Supply⁽¹⁾ $V_+ = 1.65 \text{ V}$ to 1.95 V, $T_A = -40 ^{\circ}\text{C}$ to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIO	ONS	TA	٧+	MIN	TYP	MAX	UNIT
Analog Switch									
Analog signal range	V _{COM} , V _{NC}					0		٧+	V
Peak ON resistance		$0 \le V_{NC} \le V_+$	Switch ON,	25 °C	1.65 V		3.7	25	Ω
Peak On resistance	^r peak	$I_{COM} = -2 \text{ mA},$	See Figure 13	Full	V CO.1			30	52
ON-state resistance		$V_{NC} = 1.5 V,$	Switch ON,	25°C	1.65 V		1.5	3.4	Ω
ON-State resistance	r _{on}	$I_{COM} = -2 \text{ mA},$	See Figure 13	Full	1.05 V			3.5	22
		$0 \le V_{NC} \le V_+,$		25°C			1.5		
ON-state resistance	ron(flat)	ICOM = -2 mA	Switch ON,	0500	1.65 V				Ω
flatness	On(nat)	$V_{NC} = 0.6 \text{ V}, 1.5 \text{ V},$	See Figure 13	25°C			2	6	
		ICOM = -2 mA		Full				6	
	INC(OFF)	$V_{NC} = 0.3 \text{ V}, V_{COM} = 1.65 \text{ V},$		25°C	1.95 V	-2	0.5	2	nA
NC	'NC(OFF)	$V_{NC} = 1.65 \text{ V}, V_{COM} = 0.3 \text{ V}$	Switch OFF,	Full	1.00 V	-20		20	""
OFF leakage current		V _{NC} = 0 to 1.95 V,	See Figure 14	25°C	0 V	-1	0.1	1	μΑ
	INC(PWROFF)	V _{COM} = 1.95 V to 0		Full	0 0	-5		5	
		$V_{COM} = 0.3 \text{ V}, V_{NC} = 1.65 \text{ V},$	3k 3	25°C	5	-2	0.5	2	
COM	ICOM(OFF)	or V _{COM} = 1.65 V, V _{NC} = 0.3 V	Switch OFF,	Full	1.95 V	-20		20	nA
OFF leakage current			See Figure 14	25°C			0.1	1	
	COM(PWROFF)	V _{COM} = 1.95 V to 0, V _{NC} = 0 to 1.95 V	CO	Full	0 V		0.1	5	μΑ
		V _{NC} = 0.3 V, V _{COM} = Open,		25°C		-2	0.1	2	
NC ON leakage current	INC(ON)	or	Switch ON, See Figure 15		1.95 V		0.1		nA
ON leakage current	` `	$V_{NC} = 1.65 \text{ V}, V_{COM} = \text{Open},$	Occ riguic 15	Full		-20		20	
COM	1	$V_{COM} = 0.3 \text{ V}, V_{NC} = \text{Open},$	Switch ON,	25°C	4.05.1/	-2	0.1	2	
ON leakage current	ICOM(ON)	or V _{COM} = 1.65 V, V _{NC} = Open,	See Figure 15	Full	1.95 V	-20		20	nA
Digital Control Input (IN)			1					
Input logic high	VIH			Full		1.5		5.5	V
Input logic low	VIL			Full		0		0.6	V
land balance of		V 55V == 0		25°C	4.05.1/	-2	0.3	2	^
Input leakage current	I _{IH} , I _{IL}	$V_{I} = 5.5 \text{ V or } 0$		Full	1.95 V	-20		20	nA

⁽¹⁾ The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum



SCDS187 – FEBRUARY 2005

Electrical Characteristics for 1.8-V Supply⁽¹⁾ (continued) $V_+ = 1.65 \text{ V}$ to 1.95 V, $T_A = -40 ^{\circ}\text{C}$ to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CO	NDITIONS	TA	V ₊	MIN	TYP	MAX	UNIT
Dynamic	•								
Turn-on time	tou	$V_{COM} = V_+,$	C _L = 35 pF,	25°C	1.8 V	5.5	5	19	no.
Turn-orr time	tON	$R_L = 50 \Omega$,	See Figure 17	Full	1.65 V to 1.95 V	5		20	ns
Turn-off time	torr	$V_{COM} = V_+,$	$C_L = 35 pF$,	25°C	1.8 V	7.5	12	17.5	ns
Turri on time	tOFF	$R_L = 50 \Omega$,	See Figure 17	Full	1.65 V to 1.95 V	6		20	115
Charge injection	QC	V _{GEN} = 0, R _{GEN} = 0,	C _L = 1 nF, See Figure 20	25°C	1.8 V		1		рC
NC OFF capacitance	C _{NC(OFF)}	V _{NC} = V ₊ or GND, Switch OFF,	See Figure 16	25°C	1.8 V		19		pF
COM OFF capacitance	CCOM(OFF)	V _{COM} = V ₊ or GND, Switch OFF,	See Figure 16	25°C	1.8 V		18		pF
NC ON capacitance	C _{NC(ON)}	V _{NC} = V ₊ or GND, Switch ON,	See Figure 16	25°C	1.8 V		37		pF
COM ON capacitance	CCOM(ON)	V _{COM} = V ₊ or GND, Switch ON,	See Figure 16	25°C	1.8 V		37		pF
Digital input capacitance	Cl	$V_I = V_+ \text{ or GND},$	See Figure 16	25°C	1.8 V		2		pF
Bandwidth	BW	R_L = 50 Ω, Switch ON,	See Figure 18	25°C	1.8 V		200		MHz
OFF isolation	O _{ISO}	R_L = 50 Ω, f = 1 MHz,	Switch OFF, See Figure 19	25°C	1.8 V		-64		dB
Total harmonic distortion	THD	$R_L = 600 \Omega,$ $C_L = 50 pF,$	f = 20 Hz to 20 kHz, See Figure 21	25°C	1.8 V		0.05		%
Supply	•			•					
Positive supply current	I ₊	$V_1 = V_+$ or GND,	Switch ON or OFF	25°C Full	1.95 V		0.01	0.1	μΑ

⁽¹⁾ The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum



TYPICAL PERFORMANCE

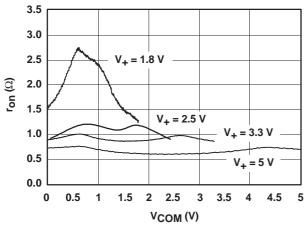


Figure 1. r_{on} vs V_{COM} ($T_A = 25^{\circ}C$)

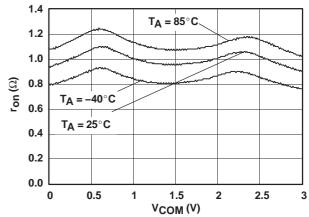


Figure 2. r_{on} vs V_{COM} ($V_{+} = 3 V$)

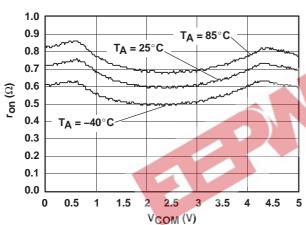


Figure 3. r_{on} vs V_{COM} ($V_{+} = 5 \text{ V}$)

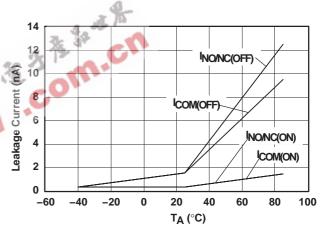


Figure 4. Leakage Current vs Temperature $(V_+ = 5.5 \text{ V})$

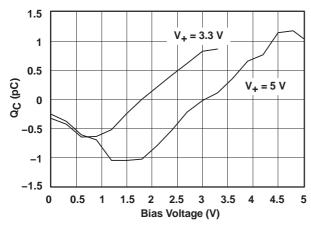


Figure 5. Charge Injection (Q_C) vs Bias Voltage

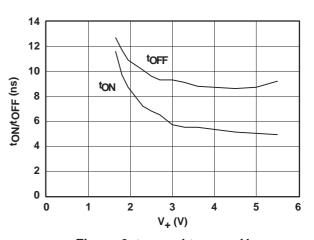
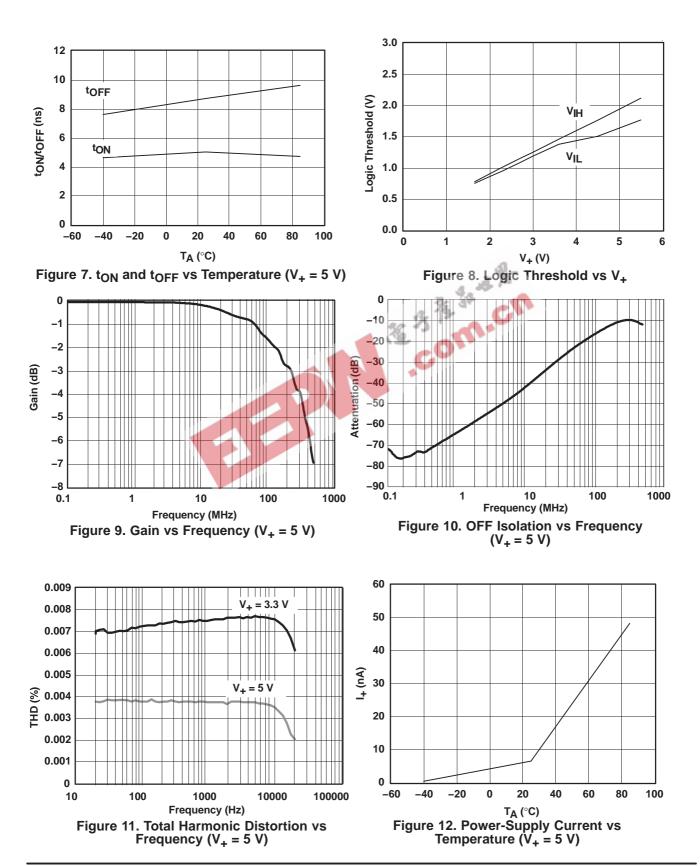


Figure 6. t_{ON} and t_{OFF} vs V_{+}



TYPICAL PERFORMANCE







PIN DESCRIPTION

PIN NUMBER	NAME	DESCRIPTION	
1	NC	Normally closed	
2	COM	Common	
3	GND	Digital ground	
4	IN	Digital control pin to connect COM to NC	
5	V ₊	Power supply	

PARAMETER DESCRIPTION

SYMBOL	DESCRIPTION			
VCOM	Voltage at COM			
V _{NC}	Voltage at NC			
r _{on}	Resistance between COM and NC ports when the channel is ON			
rpeak	Peak on-state resistance over a specified voltage range			
ron(flat)	Difference between the maximum and minimum value of ron in a channel over the specified range of conditions			
I _{NC} (OFF)	Leakage current measured at the NC port, with the corresponding channel (NC to COM) in the OFF state under worst-case input and output conditions			
INC(PWROFF)	Leakage current measured at the NC port during the power-down condition, V ₊ = 0			
ICOM(OFF)	Leakage current measured at the COM port, with the corresponding channel (COM to NC) in the OFF state under worst-case input and output conditions			
ICOM(PWROFF)	Leakage current measured at the COM port during the power-down condition, V ₊ = 0			
I _{NC(ON)}	Leakage current measured at the NC port, with the corresponding channel (NC to COM) in the ON state and the output (COM) open			
I _{COM(ON)}	Leakage current measured at the COM port, with the corresponding channel (COM to NC) in the ON state and the output (NC) open			
VIH	Minimum input voltage for logic high for the control input (IN)			
V _{IL}	Maximum input voltage for logic low for the control input (IN)			
VI	Voltage at the control input (IN)			
I _{IH} , I _{IL}	Leakage current measured at the control input (IN)			
tON	Turn-on time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog output (COM or NC) signal when the switch is turning ON.			
^t OFF	Turn-off time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog output (COM or NC) signal when the switch is turning OFF.			
QC	Charge injection is a measurement of unwanted signal coupling from the control (IN) input to the analog (NC or COM) output. This is measured in coulomb (C) and measured by the total charge induced due to switching of the control input. Charge injection, $Q_C = C_L \times \Delta V_{COM}$, C_L is the load capacitance, and ΔV_{COM} is the change in analog output voltage.			
C _{NC(OFF)}	Capacitance at the NC port when the corresponding channel (NC to COM) is OFF			
C _{COM(OFF)}	Capacitance at the COM port when the corresponding channel (COM to NC) is OFF			
C _{NC(ON)}	Capacitance at the NC port when the corresponding channel (NC to COM) is ON			
C _{COM(ON)}	Capacitance at the COM port when the corresponding channel (COM to NC) is ON			
Cl	Capacitance of control input (IN)			
O _{ISO}	OFF isolation of the switch is a measurement of OFF-state switch impedance. This is measured in dB in a specific frequency, with the corresponding channel (NC to COM) in the OFF state.			
BW	Bandwidth of the switch. This is the frequency at which the gain of an ON channel is -3 dB below the DC gain.			
	Total harmonic distortion describes the signal distortion caused by the analog switch. This is defined as the ratio of root			
THD	mean square (RMS) value of the second, third, and higher harmonic to the absolute magnitude of the fundamental harmonic.			



PARAMETER MEASUREMENT INFORMATION

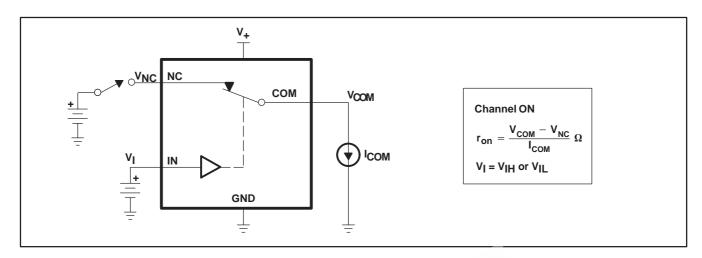
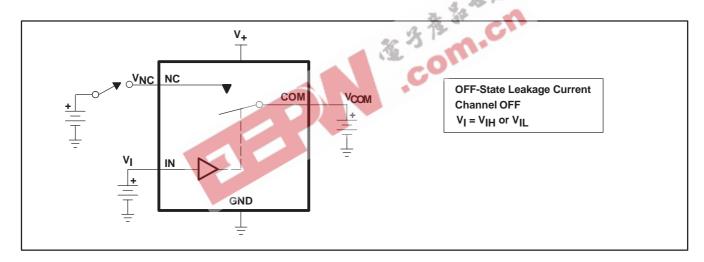


Figure 13. ON-State Resistance (ron)



 $\textbf{Figure 14. OFF-State Leakage Current (I_{COM(OFF)}, I_{NC(OFF)}, I_{COM(PWROFF)}, I_{NC(PWROFF)}) } \\$

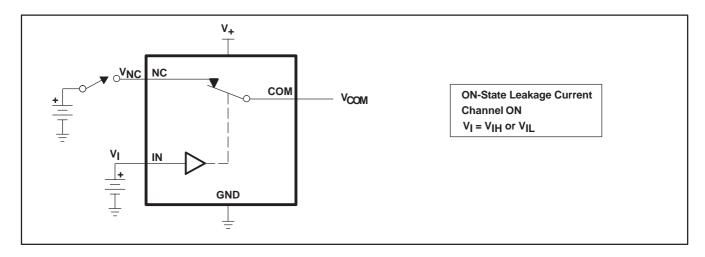


Figure 15. ON-State Leakage Current ($I_{COM(ON)}$, $I_{NC(ON)}$)



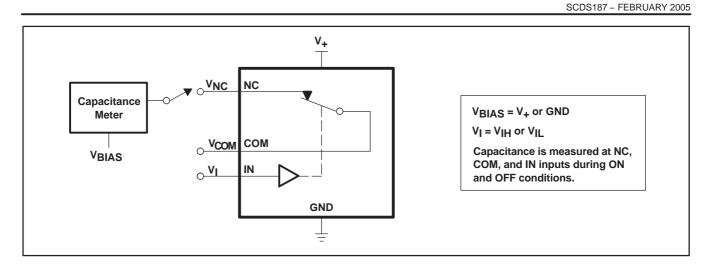
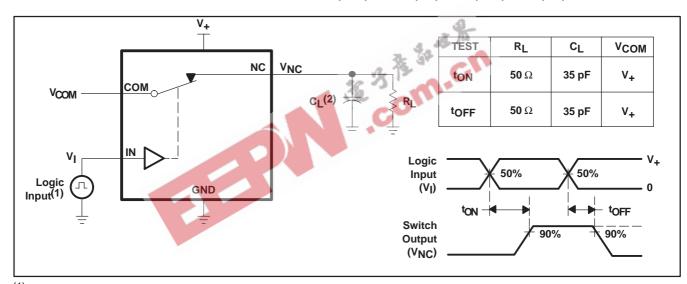


Figure 16. Capacitance (C_I , $C_{COM(OFF)}$, $C_{COM(ON)}$, $C_{NC(OFF)}$, $C_{NC(ON)}$)



- (1) All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , t_f < 5 ns.
- (2) C_L includes probe and jig capacitance.

Figure 17. Turn-On (t_{ON}) and Turn-Off Time (t_{OFF})

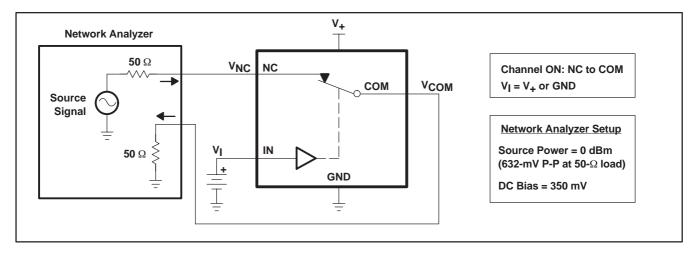


Figure 18. Bandwidth (BW)



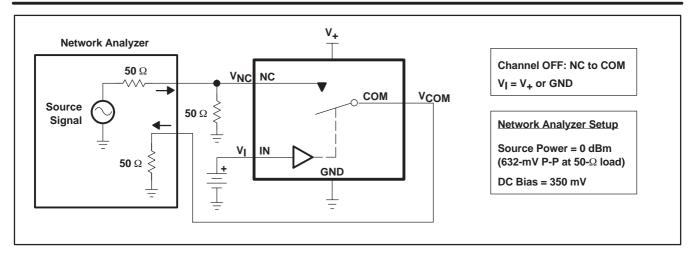
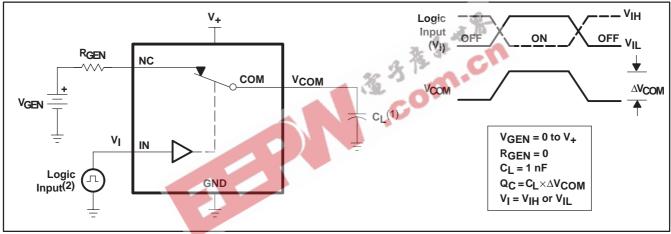
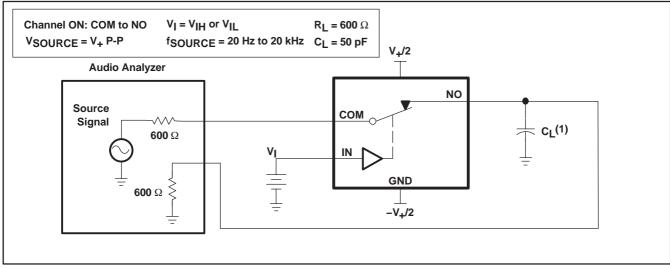


Figure 19. OFF Isolation (O_{ISO})



- (1) C_L includes probe and jig capacitance.
- (2) All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_f < 5 \text{ ns}$.

Figure 20. Charge Injection (Q_C)



(1) C_L includes probe and jig capacitance.

Figure 21. Total Harmonic Distortion (THD)



PACKAGE OPTION ADDENDUM

26-Apr-2005

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	n MSL Peak Temp ⁽³⁾
TS5A3167DBVR	ACTIVE	SOT-23	DBV	5	3000	Pb-Free (RoHS)	CU NIPDAU	Level-1-260C-UNLIM
TS5A3167DCKR	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

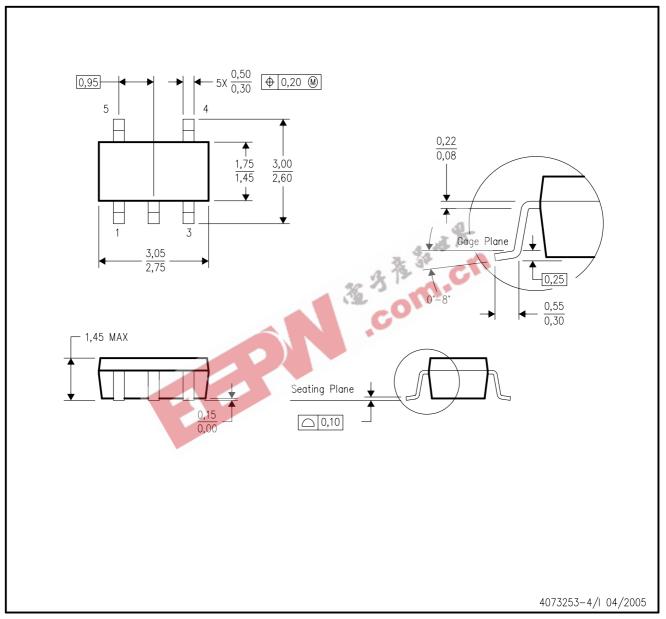
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



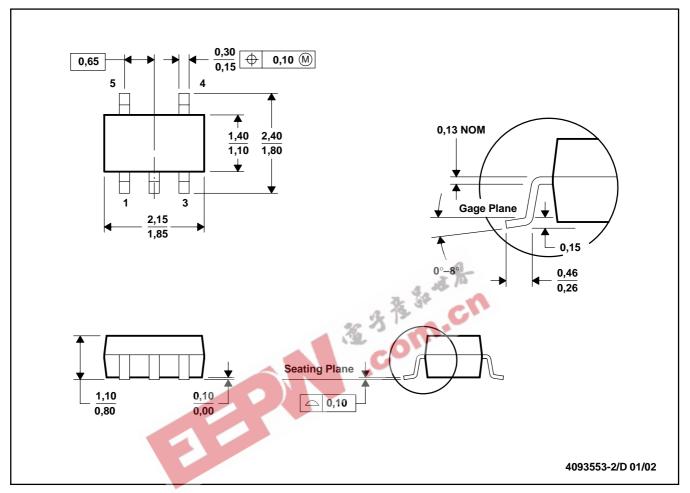
NOTES: All linear dimensions are in millimeters.

- This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion.
 D. Falls within JEDEC MO-178 Variation AA.



DCK (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion.
- D. Falls within JEDEC MO-203

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

Products		Applications	
Amplifiers	amplifier.ti.com	Audio	www.ti.com/audio
Data Converters	dataconverter.ti.com	Automotive	www.ti.com/automotive
DSP	dsp.ti.com	Broadband	www.ti.com/broadband
Interface	interface.ti.com	Digital Control	www.ti.com/digitalcontrol
Logic	logic.ti.com	Military	www.ti.com/military
Power Mgmt	power.ti.com	Optical Networking	www.ti.com/opticalnetwork
Microcontrollers	microcontroller.ti.com	Security	www.ti.com/security
		Telephony	www.ti.com/telephony
		Video & Imaging	www.ti.com/video
		Wireless	www.ti.com/wireless

Mailing Address: Texas Instruments

Post Office Box 655303 Dallas, Texas 75265

Copyright © 2005, Texas Instruments Incorporated